# **EPISTAR**

# **ES-EABCF08M**

InGaN F-series LED Chip

### > Mechanical Specification:

#### (1) Dimension

- Chip size: 8 mil x 36 mil (200  $\pm$  25  $\mu$ m x 910  $\pm$  25  $\mu$ m)

- Thickness: 4.9 mil (125  $\pm$  10  $\mu$ m) - P bonding pad: 2.4 mil (60  $\pm$  10  $\mu$ m) - N bonding pad: 2.4 mil (60  $\pm$  10  $\mu$ m)

#### (2) Metallization

Topside P electrode: Au alloyTopside N electrode: Au alloy

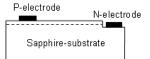
#### **Features:**

- · High radiant flux
- · 100% probing test
- · Passivation layer on top
- · Long operation life

#### **Applications:**

Backlighting





# > Electro-optical Characteristics at 25°C: (1)

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit
Forward Voltage	Vf1		If = 10μA	2.0	-	-	V
	Vf2		If = 20mA	-	2.8	3.0	V
Reverse Current	Ir		Vr = 5V	-	-	2.0	μΑ
Dominant Wavelength <sup>(2)</sup>	λd		If = 20mA	445	-	465	nm
Spectra Half-width	Δλ		If = 20mA	-	25	-	nm
Radiant Flux <sup>(3)(4)</sup>	Ро	A36	If = 20mA	40	-	42	- mW
		A37		42	-	44	

Note:

<sup>(1)</sup> ESD protection during chip handling is recommended.

<sup>(2)</sup> Basically, the wavelength span is 20nm; however, customers' special requirements are also welcome.

<sup>(3)</sup> Radiant flux is determined by using an Ag-plated TO-can header without an encapsulant.

<sup>(4)</sup> Radiant flux measurement allows a tolerance of  $\pm 15\%$ .

## > Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC Current	If	Ta = 25°C	≤ 60	mA
Reverse Voltage	Vr	Ta = 25°C	≤ 5	V
Junction Temperature	Тј	-	≤ 125	°C
		Chip	-40 ~ +85	°C
Storage Temperature	Tstg	Chip-on-tape/storage	5 ~ 35	°C
		Chip-on-tape/transportation	-20 ~ +65	°C
Temperature during Packaging	-	-	280(<10sec)	°C

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Printed Circuit Board (PCB) without an encapsulant. Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

#### > Characteristic Curves:

Fig.1 – Relative luminous Intensity vs. Forward Current

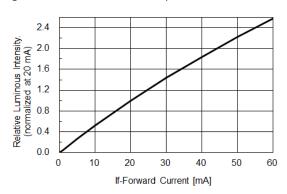


Fig.3 – Relative Intensity (@20mA) vs. Ambient Temperature

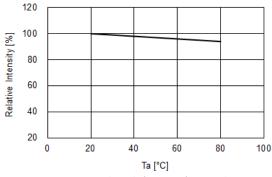


Fig.5 – Dominant Wavelength (@20mA) vs. Ambient Temperature

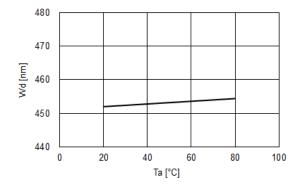


Fig.2 – Forward Current vs. Forward Voltage

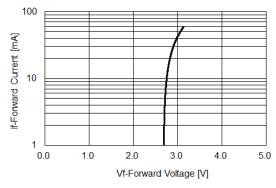
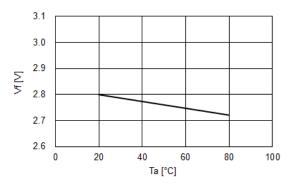


Fig.4 – Forward Voltage (@20mA) vs. Ambient Temperature



**Fig.6** – Maximum Driving Forward DC Current vs. Ambient Temperature (De-rating based on Tj max. = 125°C)

